

YJ Planar Schottky Barrier Diode Die Specification

60V 100A, 250mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB250M060AS-290A

Main Products Characteristics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

$I_F = 100A$

2%

Device Schematics and Outline Drawing

Die Thickness *